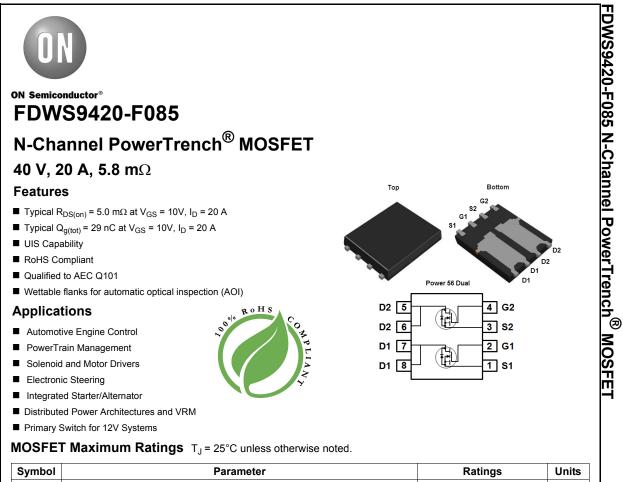
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Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-to-Source Voltage		40	V
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V
I <sub>D</sub>	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	20	Α
	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4	— A
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	98	mJ
р	Power Dissipation		75	W
P <sub>D</sub>	Derate Above 25°C		0.5	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case		2	°C/W
$R_{ extsf{ heta}JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

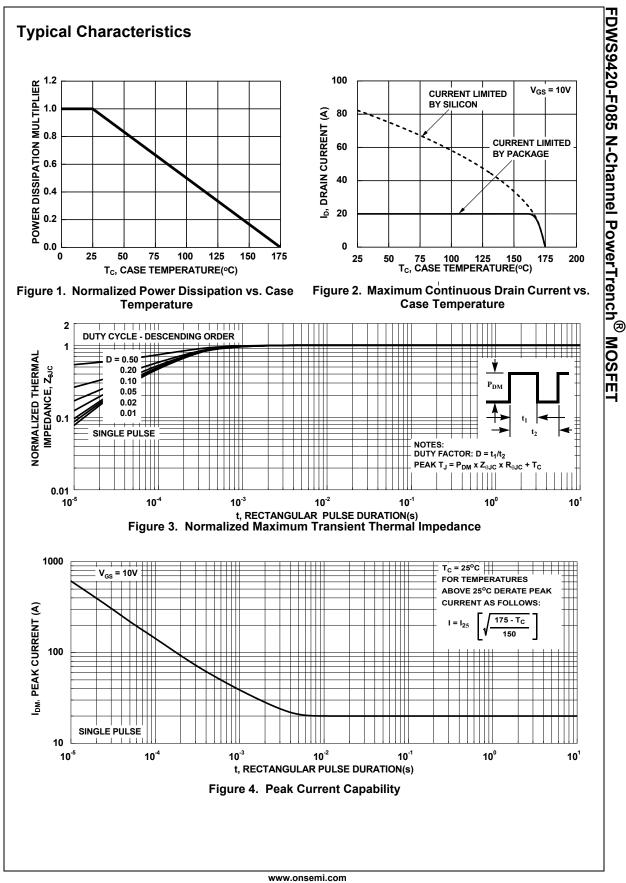
Notes:

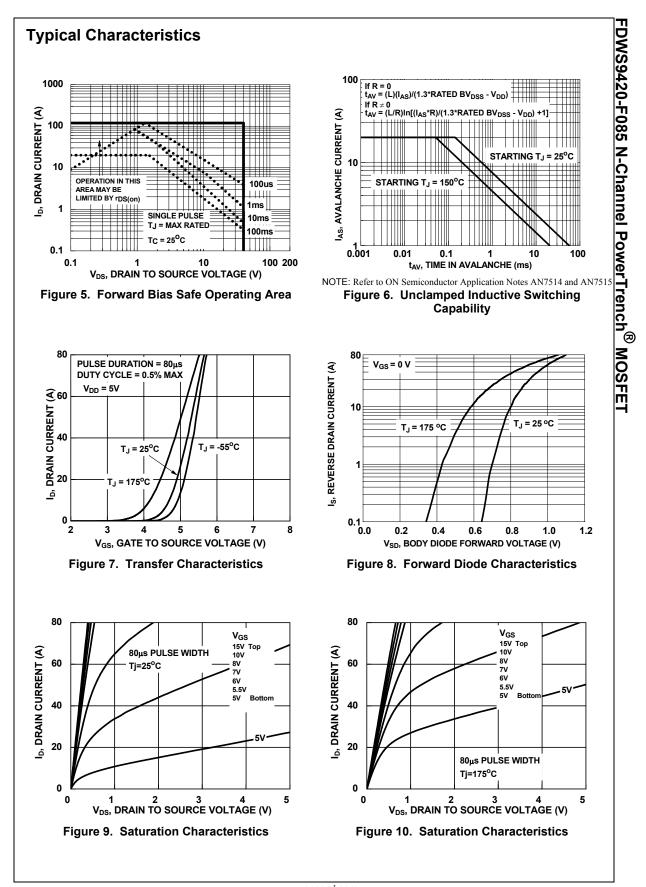
1: Current is limited by bondwire configuration. 2: Starting  $T_J = 25^{\circ}$ C, L = 1mH, I<sub>AS</sub> = 14A, V<sub>DD</sub> = 40V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche. 3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder 3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder 3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder 3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance. moduling surface of the drain pins.  $R_{\theta,JC}$  is guaranteed by design, while  $R_{\theta,JA}$  is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## Package Marking and Ordering Information

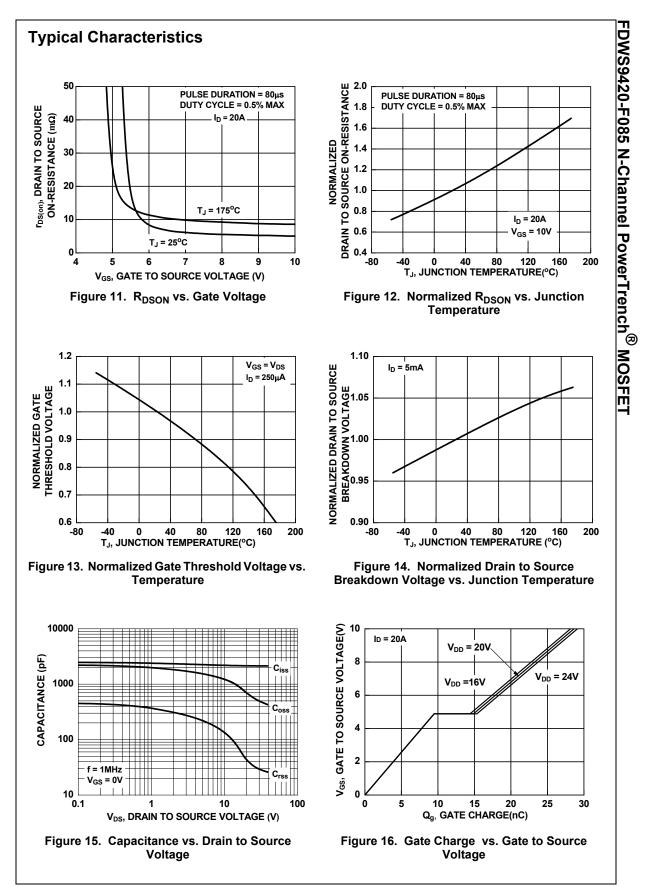
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDWS9420	FDWS9420-F085	Power56	13"	12mm	3000units

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub>	= 0V	40	-	-	V
	-	$V_{DS} = 40V, T_J = 25^{\circ}C$		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V T_J$	= 175 <sup>o</sup> C (Note 4)	-	-	1	mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	V <sub>GS</sub> = ±20V		-	-	±100	nA
On Cha	racteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D =$	250μΑ	2.0	3.0	4.0	V
R <sub>DS(on)</sub>	Drain to Source On Resistance		= 25°C	-	5.0	5.8	mΩ
			= 175°C (Note 4)	-	8.5	10.0	mΩ
-	ic Characteristics				0400		-
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz		-	2100	-	pF
C <sub>oss</sub>	Output Capacitance			-	710	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	44	-	pF
R <sub>g</sub>	Gate Resistance	f = 1MHz		-	1.8	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 20V$		-	29	43	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2V	I <sub>D</sub> = 20A	-	3.9	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge			-	9.5	-	nC
Q <sub>gd</sub>	Gate-to-Drain "Miller" Charge			-	5.4	-	nC
Switchi	ng Characteristics						
t <sub>on</sub>	Turn-On Time			-	-	29	ns
t <sub>d(on)</sub>	Turn-On Delay			-	14	-	ns
t <sub>r</sub>	Rise Time	$V_{DD} = 20V, I_D = 20A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$		-	8	-	ns
t <sub>d(off)</sub>	Turn-Off Delay			-	21	-	ns
t <sub>f</sub>	Fall Time			-	6	-	ns
t <sub>off</sub>	Turn-Off Time			-	-	35	ns
Drain-S	ource Diode Characteristics						
Var	Source-to-Drain Diode Voltage	I <sub>SD</sub> =20A, V <sub>GS</sub> = 0V		-	-	1.25	V
$V_{SD}$		$I_{SD}$ = 10A, $V_{GS}$ =	= 0V	-	-	1.2	V
t <sub>rr</sub>	Reverse-Recovery Time	$I_F = 20A, dI_{SD}/c$	lt = 100Α/μs	-	48	63	ns
Q <sub>rr</sub>	Reverse-Recovery Charge	$V_{DD} = 32V$		-	40	52	nC

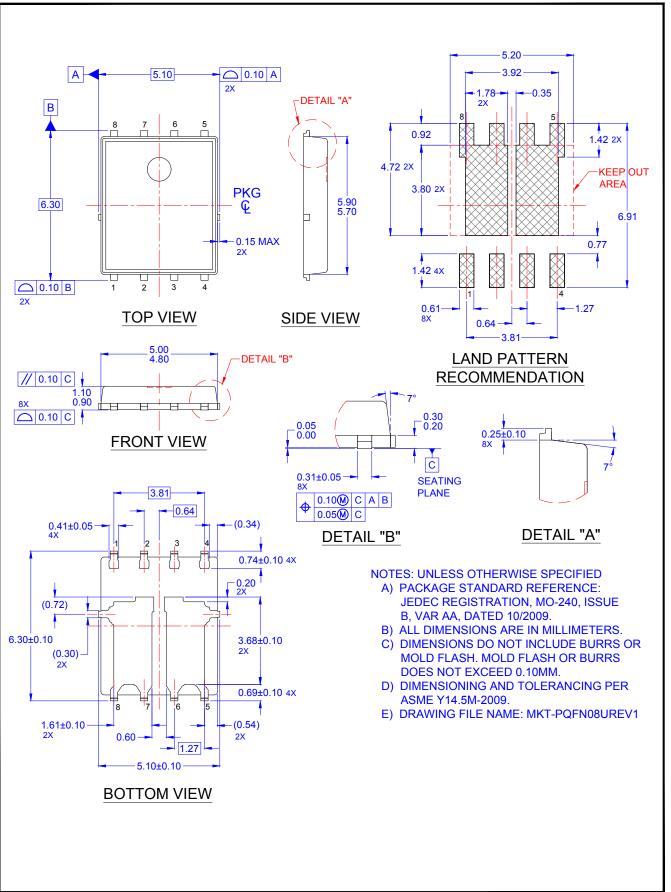




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FDWS9420-F085 N-Channel PowerTrench<sup>®</sup> MOSFET

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